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	SIA	HEMENI	BY APPLI	CANT	First Named Inventor	Yang, et al.		
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Sheet		1	of	1	Attorney Docket Number	TSM03-0929		

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Examiner Initials*	Cite No.1	Document Number Number - Kind Code ^{2 (# Mown)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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Cite No.	i de la	T ²
	CHAU, R., et al., "A 50nm Depleted-Substrate CMOS Transistor (DST)," IEDM (2001) pp. 621-624.	
	SHAHIDI, G.G., "SOI Technology for the GHz Era," IBM J. RES. & DEV., Vol. 46, No. 2/3 (March/May 2002) pp. 121-131.	-
		Cite No. Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. CHAU, R., et al., "A 50nm Depleted-Substrate CMOS Transistor (DST)," IEDM (2001) pp. 621-624. SHAHIDI, G.G., "SOI Technology for the GHz Era," IBM J. RES. & DEV. Vol. 45, No. 20, (Magazine, 2001).

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